硅烯及取代硅烯与饱和键插入反应的量子化学研究

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收稿日期 修回日期 网络版发布日期 接受日期

摘要 用量子化学的密度泛函理论(DFT)在6-311G水平上对硅烯及其取代物与甲烷的C-

H键进行插入反应的势能面进行了系统地研究。用IRC方法对过渡态进行了验证。并用组态混合模型讨论了反应势垒  $(\triangle E^+)$ 和反应热 $(\triangle H)$ 与SiXY的单-三态激发能 $\triangle$ Est的关系。我们发现,硅烯SiXY的 $\triangle$ Est是控制反应的主要因素,取代基的电负性越大,取代基越多, $\pi$ 电子给予越强,SiXY的 $\triangle$ Est就越大,插入反应的活化能就越大,放热就越小。关键词 硅烯 插入反应 密度泛涵理论 过渡态理论 甲烷 激发态

分类号 0641

# Quantum chemistry study on the insertion reaction of silylene and its substituted species to saturated bond

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Abstract The potential energy surfaces for the insertion of silylene into C-H bond of methane were studied using density functional theory (DFT). All the stationary points were determined at the BELYP/6-311G level of the theory. The transition state both to the reactant and the product direction in the reaction paths was examined by using the intrinsic reaction coordinate (IRC). A configuration mixing model has been used to explain the barrie height and the reaction enthalpy. The results show that the single-triplet splitting  $\triangle$ Est of the SiXY species plays an mportant role to predict its activity for the insertion reactions. The major conclusion is as follows: the more strong the  $\pi$ -donation is or the more electronegative the substituents are the larger the  $\triangle$ Est of SiXY, the higher the activation energy, and the smaller the exothermicity for the insertion of SiXY into saturated C-H bonds will be. In other words, it is the electronic factors, rather than the steric factors, that play a decisive role in determining the chemical reactivity of the silylene species.

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